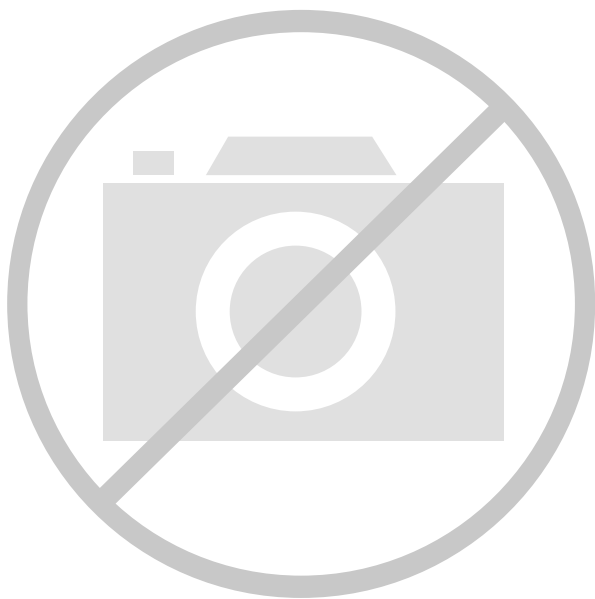




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Understanding [Embedded - Microprocessors](#)

Embedded microprocessors are specialized computing chips designed to perform specific tasks within an embedded system. Unlike general-purpose microprocessors found in personal computers, embedded microprocessors are tailored for dedicated functions within larger systems, offering optimized performance, efficiency, and reliability. These microprocessors are integral to the operation of countless electronic devices, providing the computational power necessary for controlling processes, handling data, and managing communications.

Applications of [Embedded - Microprocessors](#)

Embedded microprocessors are utilized across a broad spectrum of applications, making them indispensable in

Details

Product Status	Obsolete
Core Processor	PowerPC 603e
Number of Cores/Bus Width	1 Core, 32-Bit
Speed	200MHz
Co-Processors/DSP	-
RAM Controllers	-
Graphics Acceleration	No
Display & Interface Controllers	-
Ethernet	-
SATA	-
USB	-
Voltage - I/O	3.3V
Operating Temperature	0°C ~ 105°C (TA)
Security Features	-
Package / Case	255-BCBGA, FCCBGA
Supplier Device Package	255-FCCBGA (21x21)
Purchase URL	https://www.e-xfl.com/product-detail/nxp-semiconductors/mpc603rvg200lc

Table 1. PowerPC 603e Microprocessors from Freescale

Technical Designator	Process	Core Voltage (V)	I/O Voltage (V)	5-Volt Tolerant	Part Number
PID6-603e	0.5 μ m CMOS, 4LM	3.3	3.3	Yes	MPC603E
PID7v-603e	0.35 μ m CMOS, 5LM	2.5	3.3	Yes	XPC603P (end-of-life)
PID7t-603e	0.29 μ m CMOS, 5LM	2.5	3.3	Yes	MPC603R

1 Overview

The 603e is a low-power implementation of the PowerPC microprocessor family of RISC microprocessors. The 603e implements the 32-bit portion of the PowerPC architecture specification that provides 32-bit effective addresses, integer data types of 8, 16, and 32 bits, and floating-point data types of 32 and 64 bits. For 64-bit PowerPC microprocessors, the PowerPC architecture provides 64-bit integer data types, 64-bit addressing, and other features required to complete the 64-bit architecture.

The 603e provides four software controllable power-saving modes. Three of the modes (the nap, doze, and sleep) are static in nature, and progressively reduce the amount of power dissipated by the processor. The fourth is a dynamic power management mode that causes the functional units in the 603e to automatically enter a low-power mode when the functional units are idle without affecting operational performance, software execution, or any external hardware.

The 603e is a superscalar processor capable of issuing and retiring as many as three instructions per clock. Instructions can execute out of order for increased performance; however, the 603e makes completion appear sequential.

The 603e integrates five execution units—an integer unit (IU), a floating-point unit (FPU), a branch processing unit (BPU), a load/store unit (LSU), and a system register unit (SRU). The ability to execute five instructions in parallel and the use of simple instructions with rapid execution times yield high efficiency and throughput for 603e-based systems. Most integer instructions execute in one clock cycle. The FPU is pipelined, so a single-precision multiply-add instruction can be issued every clock cycle.

The 603e provides independent on-chip, 16-Kbyte, four-way set-associative, physically addressed caches for instructions and data and on-chip instruction and data memory management units (MMUs). The MMUs contain 64-entry, two-way, set-associative data and instruction translation lookaside buffers (DTLB and ITLB) that provide support for demand-paged virtual memory address translation and variable-sized block translation. The TLBs and caches use a least-recently used (LRU) replacement algorithm. The 603e also supports block address translation through the use of two independent instruction and data block address translation (IBAT and DBAT) arrays of four entries each. Effective addresses are compared simultaneously with all four entries in the BAT array during block translation. In accordance with the PowerPC architecture, if an effective address hits in both the TLB and BAT array, the BAT translation takes priority.

The 603e has a selectable 32- or 64-bit data bus and a 32-bit address bus. The 603e interface protocol allows multiple masters to compete for system resources through a central external arbiter. The 603e provides a three-state coherency protocol that supports the exclusive, modified, and invalid cache states. This protocol is a compatible subset of the MESI (modified/exclusive/shared/invalid) four-state protocol

- A 64-entry two-way, set-associative ITLB
- A 64-entry two-way, set-associative DTLB
- Four-entry data and instruction BAT arrays providing 128-Kbyte to 256-Mbyte blocks
- Software table search operations and updates supported through fast trap mechanism
- 52-bit virtual and 32-bit physical address
- Facilities for enhanced system performance
 - A 32- or 64-bit split-transaction external data bus with burst transfers
 - Support for one-level address pipelining and out-of-order bus transactions
- Integrated power management
 - Low-power 2.5/3.3-volt design
 - Internal processor/bus clock multiplier that provides 2:1, 2.5:1, 3:1, 3.5:1, 4:1, 4.5:1, 5:1, 5.5:1, and 6:1 ratios
 - Three power-saving modes: doze, nap, and sleep
 - Automatic dynamic power reduction when internal functional units are idle
- In-system testability and debugging features through JTAG boundary-scan capability

3 General Parameters

The following list provides a summary of the general parameters of the PID7t-603e:

Technology	0.29 μ m CMOS, five-layer metal
Die size	5.65 mm x 7.7 mm (44 mm ²)
Transistor count	2.6 million
Logic design	Fully-static
Package	255 ceramic ball grid array (CBGA) or 225 thin map plastic ball grid array (PBGA)
Core power supply	2.5 $\pm$ 5% V dc
I/O power supply	3.3 $\pm$ 5% V dc

4 Electrical and Thermal Characteristics

This section provides the AC and DC electrical specifications and thermal characteristics for the PID7t-603e.

4.1 DC Electrical Characteristics

The tables in this section describe the PID7t-603e DC electrical characteristics. This table provides the absolute maximum ratings.

This table provides the DC electrical characteristics for the PID7t-603e.

Table 5. DC Electrical Specifications

$V_{dd} = AV_{dd} = 2.5 \pm 5\% \text{ V dc}$, $OV_{dd} = 3.3 \pm 5\% \text{ V dc}$, $GND = 0 \text{ V dc}$, $0 \leq T_j \leq 105 \text{ }^\circ\text{C}$

Characteristic	Symbol	Min	Max	Unit	Note
Input high voltage (all inputs except SYSCLOCK)	V_{IH}	2.0	5.5	V	—
Input low voltage (all inputs except SYSCLOCK)	V_{IL}	GND	0.8	V	—
SYSCLOCK input high voltage	CV_{IH}	2.4	5.5	V	—
SYSCLOCK input low voltage	CV_{IL}	GND	0.4	V	—
Input leakage current, $V_{in} = 3.465 \text{ V}$	I_{in}	—	30	μA	1, 2
$V_{in} = 5.5 \text{ V}$	I_{in}	—	300	μA	1, 2
Hi-Z (off-state) leakage current, $V_{in} = 3.465 \text{ V}$	I_{TSI}	—	30	μA	1, 2
$V_{in} = 5.5 \text{ V}$	I_{TSI}	—	300	μA	1, 2
Output high voltage, $I_{OH} = -7 \text{ mA}$	V_{OH}	2.4	—	V	—
Output low voltage, $I_{OL} = 7 \text{ mA}$	V_{OL}	—	0.4	V	—
Capacitance, $V_{in} = 0 \text{ V}$, $f = 1 \text{ MHz}$ (excludes $\overline{\text{TS}}$, $\overline{\text{ABB}}$, $\overline{\text{DBB}}$, and $\overline{\text{ARTRY}}$)	C_{in}	—	10.0	pF	3
Capacitance, $V_{in} = 0 \text{ V}$, $f = 1 \text{ MHz}$ (for $\overline{\text{TS}}$, $\overline{\text{ABB}}$, $\overline{\text{DBB}}$, and $\overline{\text{ARTRY}}$)	C_{in}	—	15.0	pF	3

Notes:

1. Excludes test signals (LSSD_MODE, L1_TSTCLK, L2_TSTCLK, and JTAG signals).
2. The leakage is measured for nominal OV_{dd} and V_{dd} or both OV_{dd} and V_{dd} must vary in the same direction (for example, both OV_{dd} and V_{dd} vary by either +5% or -5%).
3. Capacitance is periodically sampled rather than 100% tested.

This table provides the power consumption for the PID7t-603e.

Table 6. Power Consumption

	Processor (CPU) Frequency							Unit
	100 MHz	133 MHz	166 MHz	200 MHz	233 MHz	266 MHz	300 MHz	
Full-On Mode (DPM Enabled)								
Typical	1.1	1.6	2.1	2.5	3.0	3.5	4.0	W
Maximum	1.6	2.4	3.2	4.0	4.6	5.3	6.0	W
Doze Mode								
Typical	0.55	0.7	0.9	1.1	1.3	1.5	1.8	W
Nap Mode								
Typical	50	60	75	85	100	120	130	mW
Sleep Mode								
Typical	45	50	55	65	75	90	100	mW
Sleep Mode—PLL Disabled								

Table 6. Power Consumption (continued)

	Processor (CPU) Frequency							Unit
	100 MHz	133 MHz	166 MHz	200 MHz	233 MHz	266 MHz	300 MHz	
Typical	40	40	40	40	40	40	40	mW
Sleep Mode—PLL and SYSCLK Disabled								
Typical	15	15	15	15	15	15	15	mW
Maximum	25	25	25	25	25	80	100	mW

Note:

1. These values apply for all valid PLL_CFG[0–3] settings and do not include output driver power (OV_{dd}) or analog supply power (AV_{dd}). OV_{dd} power is system dependent but is typically $\leq 10\%$ of V_{dd} . Worst-case $AV_{dd} = 15$ mW.
2. Typical power is an average value measured at $V_{dd} = AV_{dd} = 2.5$ V, $OV_{dd} = 3.3$ V, in a system executing typical applications and benchmark sequences.
3. Maximum power is measured at 2.625 V using a worst-case instruction mix.

4.2 AC Electrical Characteristics

This section provides the AC electrical characteristics for the PID7t-603e. These specifications are for 200, 266, and 300 MHz processor speed grades. The processor core frequency is determined by the bus (SYSCLK) frequency and the settings of the PLL_CFG[0–3] signals. All timings are specified relative to the rising edge of SYSCLK. PLL_CFG signals should be set prior to power up and not altered afterwards.

4.2.1 Clock AC Specifications

This table provides the clock AC timing specifications as defined in Figure 1. After fabrication, parts are sorted by maximum processor core frequency as shown in Section 4.2.1, “Clock AC Specifications,” and tested for conformance to the AC specifications for that frequency. Parts are sold by maximum processor core frequency; see Section 9, “Ordering Information.”

Table 7. Clock AC Timing Specifications

 $V_{dd} = AV_{dd} = 2.5 \pm 5\%$ V dc, $OV_{dd} = 3.3 \pm 5\%$ V dc, GND = 0 V dc, $0 \leq T_j \leq 105$ °C

Num	Characteristic	200 MHz PBGA		200 MHz CBGA		266 MHz CBGA		300 MHz CBGA		Unit	Note
		Min	Max	Min	Max	Min	Max	Min	Max		
	Processor frequency	100	200	80	200	150	266	180	300	MHz	1, 6
	VCO frequency	300	400	300	400	300	532	360	600	MHz	1
	SYSCLK frequency	25	66.67	25	66.67	25	75	33.3	75	MHz	1
1	SYSCLK cycle time	13.3	40	13.3	40	13.3	40	13.3	30	ns	
2, 3	SYSCLK rise and fall time	—	2.0	—	2.0	—	2.0	—	2.0	ns	2
4	SYSCLK duty cycle measured at 1.4 V	40.0	60.0	40.0	60.0	40.0	60.0	40.0	60.0	%	3

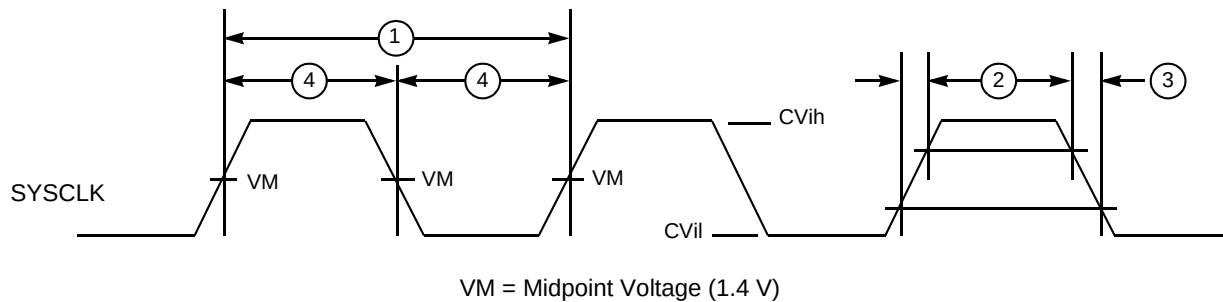
Table 7. Clock AC Timing Specifications (continued)
 $V_{dd} = AV_{dd} = 2.5 \pm 5\% \text{ V dc}$, $OV_{dd} = 3.3 \pm 5\% \text{ V dc}$, $GND = 0 \text{ V dc}$, $0 \leq T_j \leq 105 \text{ }^\circ\text{C}$

Num	Characteristic	200 MHz PBGA		200 MHz CBGA		266 MHz CBGA		300 MHz CBGA		Unit	Note
		Min	Max	Min	Max	Min	Max	Min	Max		
	SYSClk jitter	—	±150	—	±150	—	±150	—	±150	ps	4
	PID7t internal PLL-relock time	—	100	—	100	—	100	—	100	μs	3, 5

Note:

- Caution:** The SYSClk frequency and PLL_CFG[0–3] settings must be chosen such that the resulting SYSClk (bus) frequency, CPU (core) frequency, and PLL (VCO) frequency do not exceed their respective maximum or minimum operating frequencies. Refer to the PLL_CFG[0–3] signal description in [Section 8, “System Design Information,”](#) for valid PLL_CFG[0–3] settings.
- Rise and fall times for the SYSClk input are measured from 0.4 V to 2.4 V.
- Timing is guaranteed by design and characterization, and is not tested.
- Cycle-to-cycle jitter, and is guaranteed by design. The total input jitter (short term and long term combined) must be under ±150 ps to guarantee the input/output timing of [Section 4.2.2, “Input AC Specifications,”](#) and [Section 4.2.3, “Output AC Specifications.”](#)
- Relock timing is guaranteed by design and characterization, and is not tested. PLL-relock time is the maximum time required for PLL lock after a stable V_{dd} , OV_{dd} , AV_{dd} , and SYSClk are reached during the power-on reset sequence. This specification also applies when the PLL has been disabled and subsequently re-enabled during sleep mode. Also note that HRESET must be held asserted for a minimum of 255 bus clocks after the PLL-relock time (100 μs) during the power-on reset sequence.
- Operation below 150 MHz is supported only by PLL_CFG[0–3] = 0b0101. Refer to [Section 8.1, “PLL Configuration”](#) for additional information.

This figure provides the SYSClk input timing diagram.


Figure 1. SYSClk Input Timing Diagram

4.2.2 Input AC Specifications

This table provides the input AC timing specifications for the PID7t-603e as defined in [Figure 2](#) and [Figure 3](#).

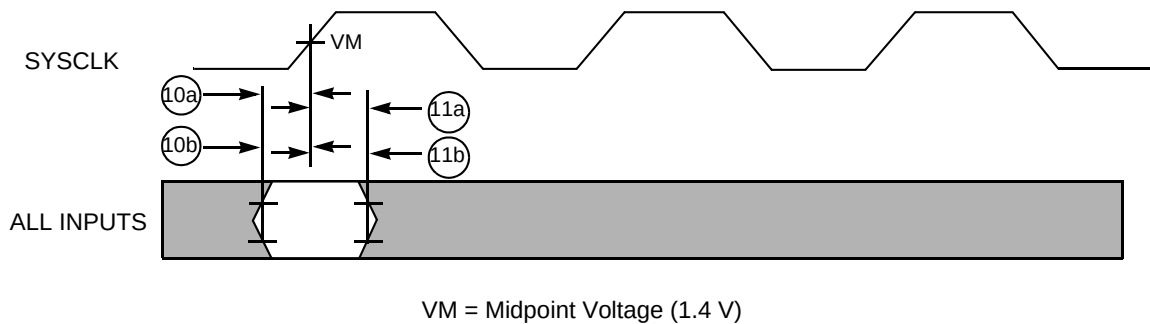
Table 8. Input AC Timing Specifications¹
 $V_{dd} = AV_{dd} = 2.5 \pm 5\% \text{ V dc}$, $OV_{dd} = 3.3 \pm 5\% \text{ V dc}$, $GND = 0 \text{ V dc}$, $0 \leq T_j \leq 105^\circ \text{ C}$

Num	Characteristic	200, 266, 300 MHz		Unit	Notes
		Min	Max		
10a	Address/data/transfer attribute inputs valid to SYSCLK (input setup)	2.5	—	ns	2
10b	All other inputs valid to SYSCLK (input setup)	3.5	—	ns	3
10c	Mode select inputs valid to $\overline{\text{HRESET}}$ (input setup) (for $\overline{\text{DRTRY}}$, $\overline{\text{QACK}}$ and $\overline{\text{TLBISYNC}}$)	8	—	t_{sysclk}	4, 5, 6, 7
11a	SYSCLK to address/data/transfer attribute inputs invalid (input hold)	1.0	—	ns	2
11b	SYSCLK to all other inputs invalid (input hold)	1.0	—	ns	3
11c	$\overline{\text{HRESET}}$ to mode select inputs invalid (input hold) (for $\overline{\text{DRTRY}}$, $\overline{\text{QACK}}$, and $\overline{\text{TLBISYNC}}$)	0	—	ns	4, 6, 7

Note:

- Input specifications are measured from the TTL level (0.8 or 2.0 V) of the signal in question to the 1.4 V of the rising edge of the input SYSCLK. Input and output timings are measured at the pin.
- Address/data/transfer attribute input signals are composed of the following—A[0–31], AP[0–3], TT[0–4], TC[0–1], $\overline{\text{TBS}}$, TSIZ[0–2], $\overline{\text{GBL}}$, DH[0–31], DL[0–31], DP[0–7].
- All other input signals are composed of the following— $\overline{\text{TS}}$, $\overline{\text{ABB}}$, $\overline{\text{DBB}}$, $\overline{\text{ARTRY}}$, $\overline{\text{BG}}$, $\overline{\text{AACK}}$, $\overline{\text{DBG}}$, $\overline{\text{DBWO}}$, $\overline{\text{TA}}$, $\overline{\text{DRTRY}}$, $\overline{\text{TEA}}$, $\overline{\text{DBDIS}}$, $\overline{\text{HRESET}}$, $\overline{\text{SRESET}}$, $\overline{\text{INT}}$, $\overline{\text{SMI}}$, $\overline{\text{MCP}}$, $\overline{\text{TBEN}}$, $\overline{\text{QACK}}$, $\overline{\text{TLBISYNC}}$.
- The setup and hold time is with respect to the rising edge of $\overline{\text{HRESET}}$ (see Figure 3).
- t_{sysclk} is the period of the external clock (SYSCLK) in nanoseconds (ns). The numbers given in the table must be multiplied by the period of SYSCLK to compute the actual time duration (in nanoseconds) of the parameter in question.
- These values are guaranteed by design, and are not tested.
- This specification is for configuration mode only. Also note that $\overline{\text{HRESET}}$ must be held asserted for a minimum of 255 bus clocks after the PLL-relock time during the power-on reset sequence.

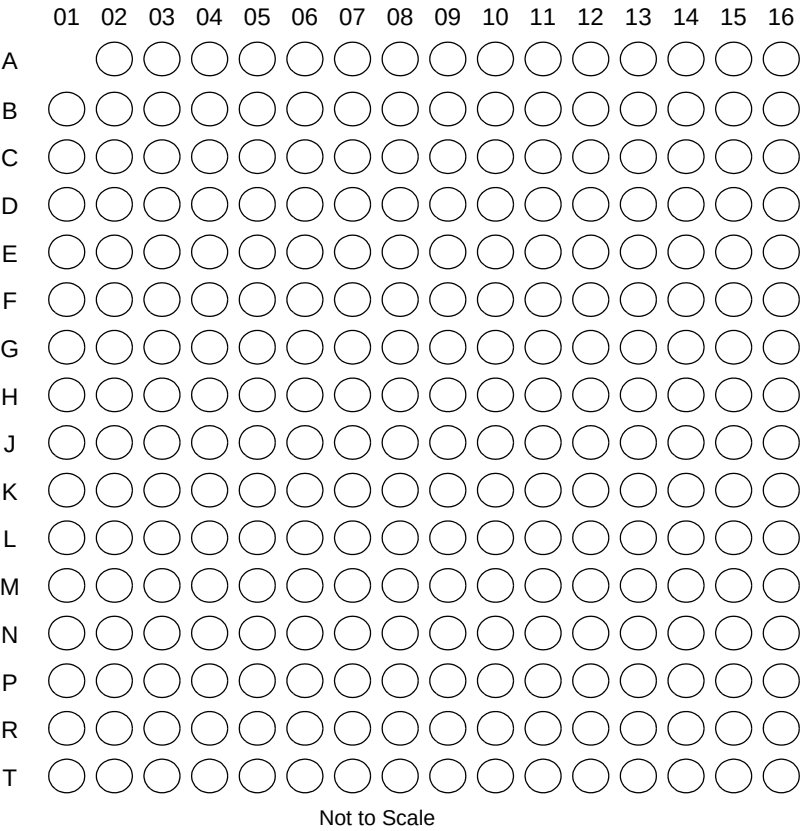
This figure provides the input timing diagram for the PID7t-603e.


Figure 2. Input Timing Diagram

5 Pin Assignments

Part A of [Figure 9](#) shows the pinout of the CBGA package as viewed from the top surface. Part B shows the side profile of the CBGA package to indicate the direction of the top surface view. The PBGA package has an identical pinout. Part C shows the side profile of the PBGA package to indicate the direction of the top surface view.

Part A



Part B

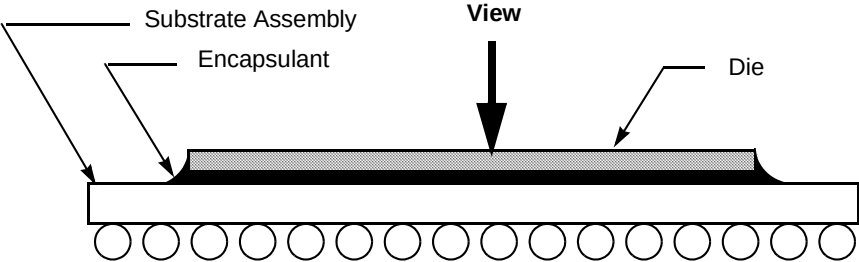


Table 11. Pinout Listing for the 255-Pin CBGA and PBGA Packages (continued)

Signal Name	Pin Number	Active	I/O
DP[0–7]	M02, L03, N02, L04, R01, P02, M04, R02	High	I/O
DPE	A05	Low	O
DRTRY	G16	Low	I
GBL	F01	Low	I/O
GND	C05, C12, E03, E06, E08, E09, E11, E14, F05, F07, F10, F12, G06, G08, G09, G11, H05, H07, H10, H12, J05, J07, J10, J12, K06, K08, K09, K11, L05, L07, L10, L12, M03, M06, M08, M09, M11, M14, P05, P12	—	—
HRESET	A07	Low	I
INT	B15	Low	I
L1_TSTCLK ¹	D11	—	I
L2_TSTCLK ¹	D12	—	I
LSSD_MODE ¹	B10	Low	I
MCP	C13	Low	I
NC (No-Connect)	B07, B08, C03, C06, C08, D05, D06, H04, J16	—	—
OV _{DD}	C07, E05, E07, E10, E12, G03, G05, G12, G14, K03, K05, K12, K14, M05, M07, M10, M12, P07, P10	—	—
PLL_CFG[0–3]	A08, B09, A09, D09	High	I
QACK	D03	Low	I
QREQ	J03	Low	O
RSRV	D01	Low	O
SMI	A16	Low	I
SRESET	B14	Low	I
SYSCLK	C09	—	I
TA	H14	Low	I
TBEN	C02	High	I
TBST	A14	Low	I/O
TC[0–1]	A02, A03	High	O
TCK	C11	—	I
TDI	A11	High	I
TDO	A12	High	O
TEA	H13	Low	I
TLBISYNC	C04	Low	I
TMS	B11	High	I
TRST	C10	Low	I

Table 11. Pinout Listing for the 255-Pin CBGA and PBGA Packages (continued)

Signal Name	Pin Number	Active	I/O
TS	J13	Low	I/O
TSIZ[0–2]	A13, D10, B12	High	O
TT[0–4]	B13, A15, B16, C14, C15	High	I/O
WT	D02	Low	O
V_{DD}^2	F06, F08, F09, F11, G07, G10, H06, H08, H09, H11, J06, J08, J09, J11, K07, K10, L06, L08, L09, L11	—	—
VOLTDGND ³	F03	Low	O

Note:

1. These are test signals for factory use only and must be pulled up to OV_{dd} for normal machine operation.
2. OV_{dd} inputs supply power to the I/O drivers and V_{dd} inputs supply power to the processor core.
3. NC (no-connect) in the PID6-603e; internally tied to GND in the PID7v-603e and PID7t-603e CBGA and PBGA package to indicate to the power supply that a low-voltage processor is present.

7 Package Descriptions

The following sections provide the CBGA and PBGA package parameters and the mechanical dimensions for the 603e.

7.1 CBGA Package Description

The following sections provide the package parameters and mechanical dimensions for the CBGA package.

7.1.1 Package Parameters

The package parameters are as provided in the following list. The package type is 21 mm x 21 mm, 255-lead ceramic ball grid array (CBGA).

Package outline	21 mm x 21 mm
Interconnects	255
Pitch	1.27 mm (50 mil)
Package height	Minimum: 2.45 mm Maximum: 3.00 mm
Ball diameter	0.89 mm (35 mil)
Maximum heat sink force	10 lbs

7.1.2 Mechanical Dimensions of the CBGA Package

This figure provides the mechanical dimensions and bottom surface nomenclature of the CBGA package.

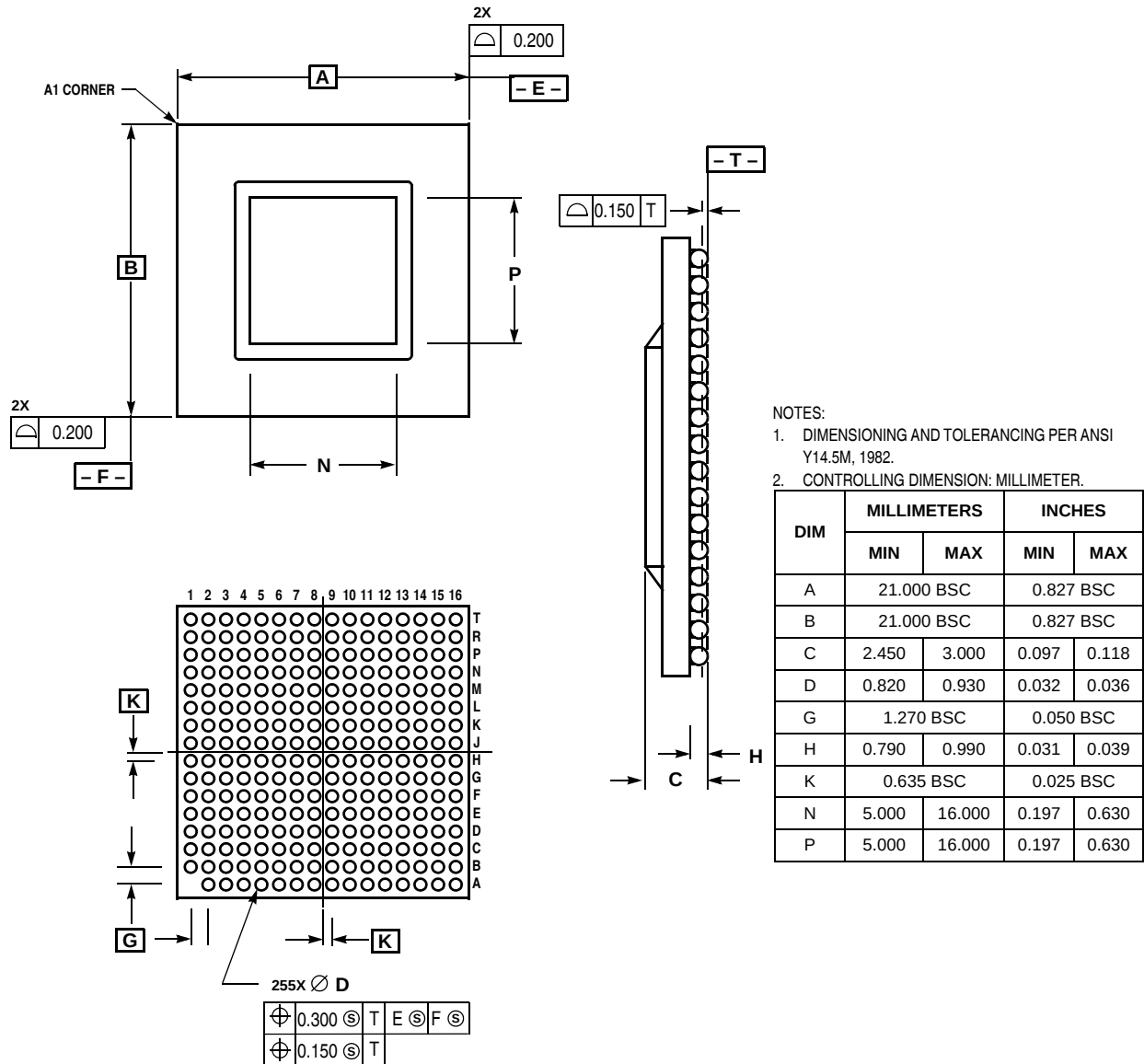


Figure 10. Mechanical Dimensions and Bottom Surface Nomenclature of the CBGA Package

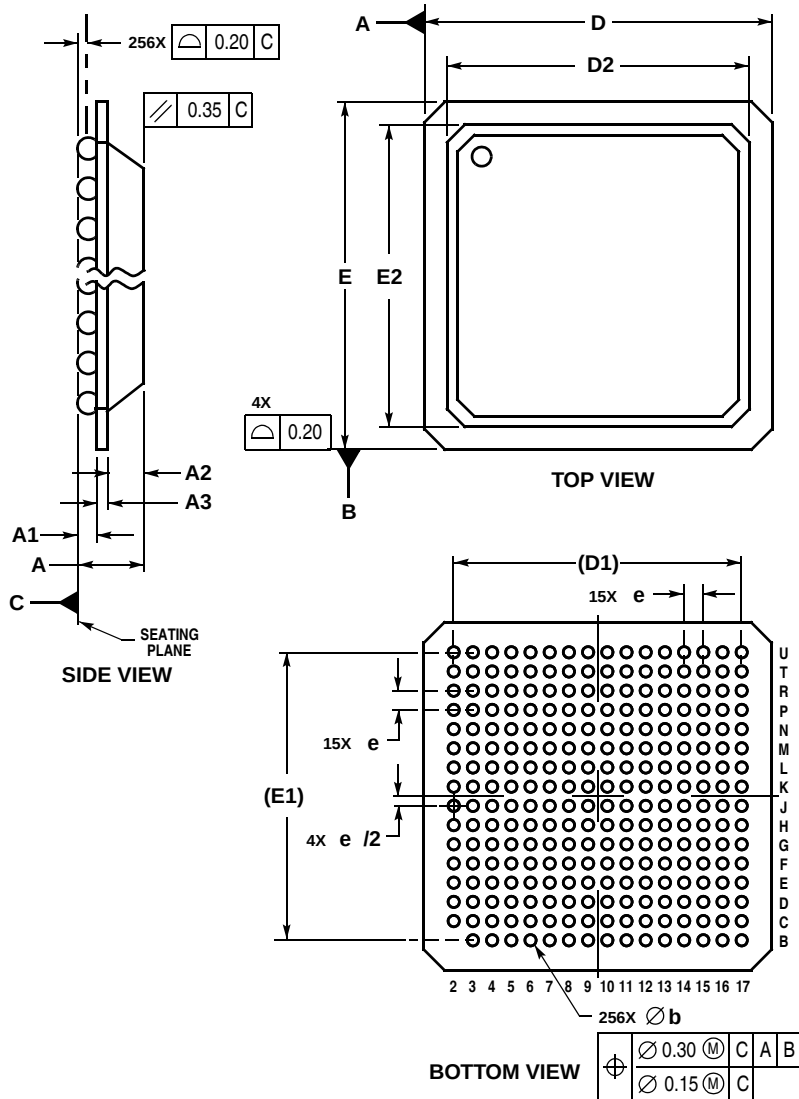
7.2 PBGA Package Description

The following sections provide the package parameters and mechanical dimensions.

7.2.1 Package Parameters

The package type is 23 mm x 23 mm, 255-lead plastic ball grid array (PBGA).

Package outline 23 mm x 23 mm



- NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 2. DIMENSIONS IN MILLIMETERS.
 3. DIMENSION b IS MEASURED AT THE MAXIMUM SOLDER BALL DIAMETER, PARALLEL TO PRIMARY DATUM C.
 4. PRIMARY DATUM C AND THE SEATING PLANE ARE

MILLIMETERS		
DIM	MIN	MAX
A	2.10	2.60
A1	0.50	0.70
A2	1.10	1.20
A3	0.50	0.70
b	0.60	0.90
D	23.00 BSC	
D1	19.05 REF	
D2	19.40	19.60
E	23.00 BSC	
E1	19.05 REF	
E2	19.40	19.60
e	1.27 BSC	

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Figure 12. Package Dimensions for the Plastic Ball Grid Array (PBGA)—JEDEC Standard

Note that the pin numberings shown in Figure 12 do not match Table 11; the pinout of the non-JEDEC standard package (and the CBGA pinout) is shown in Figure 11. Note that Figure 11 should be used in conjunction with Table 11 for the complete pinout description.

8 System Design Information

This section provides electrical and thermal design recommendations for successful application of 603e.

8.1 PLL Configuration

The 603e PLL is configured by the PLL_CFG[0–3] signals. For a given SYSCLK (bus) frequency, the PLL configuration signals set the internal CPU and VCO frequency of operation. The PLL configuration for the PID7t-603e is shown in this table for nominal frequencies.

Table 12. PLL Configuration

PLL_CFG[0:3]	CPU Frequency in MHz (VCO Frequency in MHz)								
	Bus-to-Core Multiplier	Core-to-VCO Multiplier	Bus 25 MHz	Bus 33.33 MHz	Bus 40 MHz	Bus 50 MHz	Bus 60 MHz	Bus 66.67 MHz	Bus 75 MHz
0100	2x	2x	—	—	—	—	—	—	150 (300)
0101	2x	4x	—	—	80 ⁴ (320)	100 (400)	120 (480)	133 (532)	150 (600)
0110	2.5x	2x	—	—	—	—	150 (300)	166 (333)	187 (375)
1000	3x	2x	—	—	—	150 (300)	180 (360)	200 (400)	225 (450)
1110	3.5x	2x	—	—	—	175 (350)	210 (420)	233 (466)	263 (525)
1010	4x	2x	—	—	160 (320)	200 (400)	240 (480)	267 (533)	300 (600)
0111	4.5x	2x	—	150 (300)	180 (360)	225 (450)	270 (540)	300 (600)	—
1011	5x	2x	—	166 (333)	200 (400)	250 (500)	300 (600)	—	—
1001	5.5x	2x	—	183 (366)	220 (440)	275 (550)	—	—	—
1101	6x	2x	150 (300)	200 (400)	240 (480)	300 (600)	—	—	—
0011	PLL bypass								
1111	Clock off								

Note:

- Some PLL configurations may select bus, CPU, or VCO frequencies which are not supported; see [Section 4.2.1, "Clock AC Specifications,"](#) for valid SYSCLK and VCO frequencies.
- In PLL-bypass mode, the SYSCLK input signal clocks the internal processor directly, the PLL is disabled, and the bus mode is set for 1:1 mode operation. This mode is intended for factory use only.
Note: The AC timing specifications given in this document do not apply in PLL-bypass mode.
- In clock-off mode, no clocking occurs inside the 603e regardless of the SYSCLK input.
- 80 MHz operation is not supported for the PBGA package (see [Table 7](#)).

8.2 PLL Power Supply Filtering

The AV_{dd} power signal is provided on the 603e to provide power to the clock generation phase-locked loop. To ensure stability of the internal clock, the power supplied to the AV_{dd} input signal should be filtered

using a circuit similar to the one shown in Figure 13. The circuit should be placed as close as possible to the AV_{dd} pin to ensure it filters out as much noise as possible. The $0.1\ \mu\text{F}$ capacitor should be closest to the AV_{dd} pin, followed by the $10\ \mu\text{F}$ capacitor, and finally the $10\ \Omega$ resistor to V_{dd} . These traces should be kept short and direct.

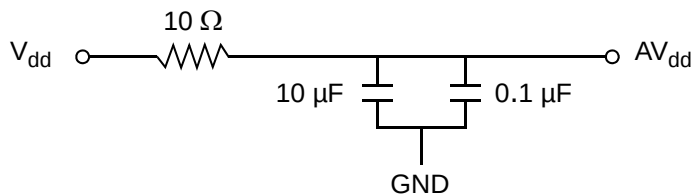


Figure 13. PLL Power Supply Filter Circuit

8.3 Decoupling Recommendations

Due to the 603e's dynamic power management feature, large address, data buses, and high-operating frequencies, it can generate transient power surges and high-frequency noise in its power supply, especially while driving large capacitive loads. This noise must be prevented from reaching other components in the 603e system. It requires a clean, tightly regulated source of power. Therefore, it is recommended that the system designer places at least one decoupling capacitor at each V_{dd} and OV_{dd} pin of the 603e. It is also recommended that these decoupling capacitors receive their power from separate V_{dd} , OV_{dd} , and GND power planes in the PCB, utilizing short traces to minimize inductance.

These capacitors should vary in value from $220\ \text{pF}$ to $10\ \mu\text{F}$ to provide both high- and low-frequency filtering, and should be placed as close as possible to their associated V_{dd} or OV_{dd} pin. Suggested values for the V_{dd} pins are: $220\ \text{pF}$ (ceramic), $0.01\ \mu\text{F}$ (ceramic), and $0.1\ \mu\text{F}$ (ceramic). Suggested values for the OV_{dd} pins are: $0.01\ \mu\text{F}$ (ceramic), $0.1\ \mu\text{F}$ (ceramic), and $10\ \mu\text{F}$ (tantalum). Only SMT capacitors should be used to minimize lead inductance.

In addition, it is recommended that there be several bulk storage capacitors distributed around the PCB, feeding the V_{dd} and OV_{dd} planes, to enable quick recharging of the smaller chip capacitors. These bulk capacitors should also have a low ESR (equivalent series resistance) rating to ensure the quick response time necessary. They should also be connected to the power and ground planes through two vias to minimize inductance. Suggested bulk capacitors— $100\ \mu\text{F}$ (AVX TPS tantalum) or $330\ \mu\text{F}$ (AVX TPS tantalum).

8.4 Connection Recommendations

To ensure reliable operation, it is highly recommended to connect unused inputs to an appropriate signal level. Unused active low inputs should be tied to V_{dd} . Unused active high inputs should be connected to GND. All NC (no-connect) signals must remain unconnected. Power and ground connections must be made to all external V_{dd} , OV_{dd} , and GND pins of the 603e.

8.5 Pull-up Resistor Requirements

The 603e requires high-resistive (weak: 10 K Ω) pull-up resistors on several control signals of the bus interface to maintain the control signals in the negated state after they have been actively negated and released by the 603e or other bus master. These signals are: $\overline{TS}$, $\overline{ABB}$, $\overline{DBB}$, and $\overline{ARTRY}$.

In addition, the 603e has three open-drain style outputs that require pull-up resistors (weak or stronger: 4.7 K Ω –10 K Ω) if they are used by the system. These signals are: $\overline{APE}$, $\overline{DPE}$, and $\overline{CKSTP_OUT}$.

During inactive periods on the bus, the address and transfer attributes on the bus are not driven by any master and may float in the high-impedance state for relatively long periods of time. Since the 603e must continually monitor these signals for snooping, this float condition may cause excessive power draw by the input receivers on the 603e. It is recommended that these signals be pulled up through weak (10 K Ω) pull-up resistors or restored in some manner by the system. The snooped address and transfer attribute inputs are—A[0–31], AP[0–3], TT[0–4], $\overline{TBST}$, and $\overline{GBL}$.

The data bus input receivers are normally turned off when no read operation is in progress and do not require pull-up resistors on the data bus.

8.6 Thermal Management Information

This section provides thermal management information for the CBGA and PBGA packages for air-cooled applications. Proper thermal control design is primarily dependent upon the system-level design—the heat sink, airflow and thermal interface material.

This figure shows the upper and lower limits of the die junction-to-ambient thermal resistance for both package styles. The lower limit is shown for the case of a densely populated PCB with high thermal loading of adjacent and neighboring components.

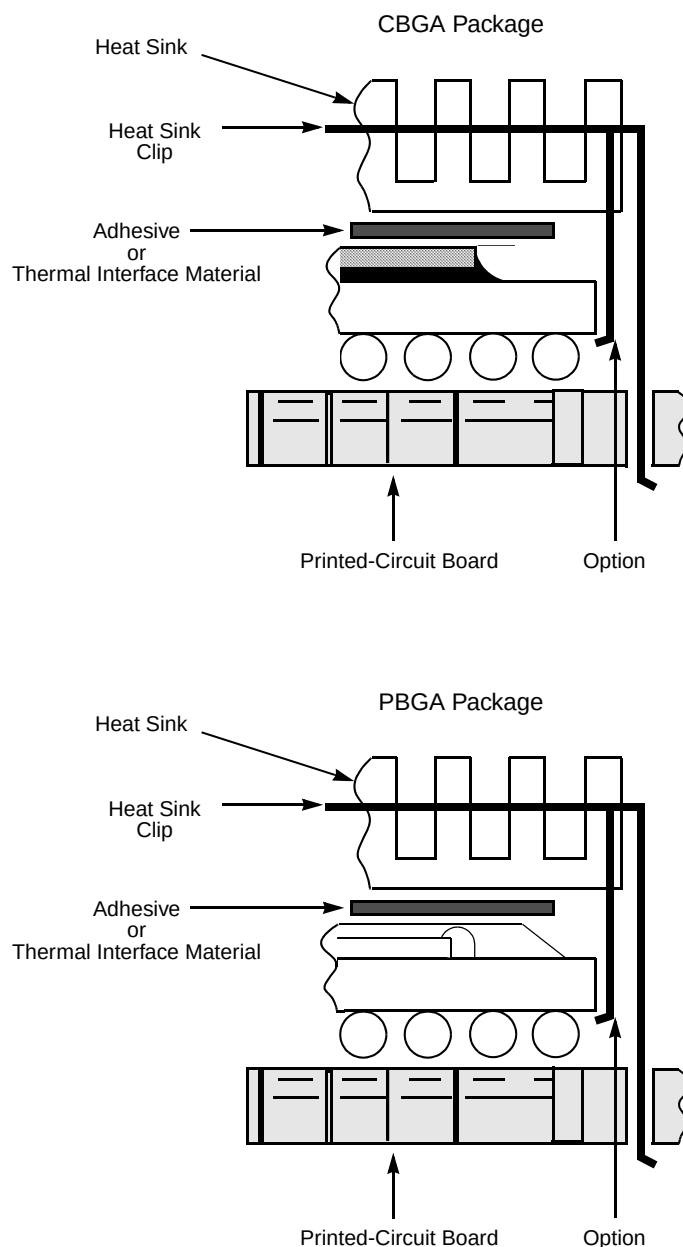


Figure 15. Package Exploded Cross-Sectional View with Heat Sink

The board designer can choose between several types of commercially available heat sinks to place on the 603e. Ultimately, the final selection of an appropriate heat sink depends on many factors, such as thermal performance at a given air velocity, spatial volume, mass, attachment method, assembly, and cost.

8.6.1 Internal Package Conduction Resistance

For this packaging technology, the intrinsic thermal conduction resistance (as shown in [Table 3](#)) versus the external thermal resistance paths are shown in this figure for a package with an attached heat sink mounted to a PCB.

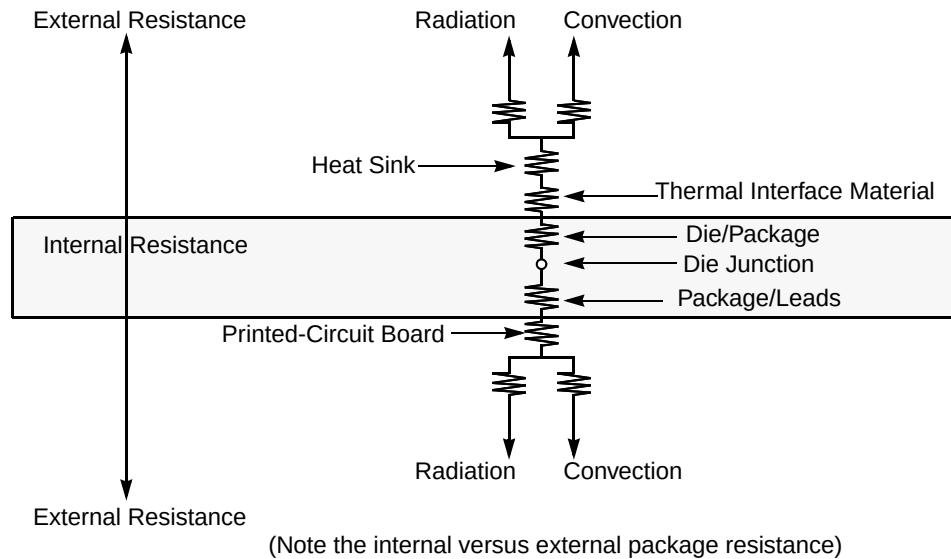


Figure 16. Package with Heat Sink Mounted to a Printed-Circuit Board

8.6.2 Thermal Interface Materials

A thermal interface material is recommended at the package lid-to-heat sink interface to minimize the thermal contact resistance. For those applications where the heat sink is attached by spring clip mechanism, as shown in [Figure 17](#). The thermal performance of three thin-sheet thermal-interface materials (silicone, graphite/oil, fluoroether oil), a bare joint, and a joint with thermal grease as a function of contact pressure. As shown, the performance of these thermal interface materials improves with increasing contact pressure. The use of thermal grease significantly reduces the interface thermal resistance. That is, the bare joint results in a thermal resistance approximately seven times greater than the thermal grease joint. Therefore, the synthetic grease offers the best thermal performance, considering the low-interface pressure. Of course, the selection of any thermal interface material depends on many factors—thermal performance requirements, manufacturability, service temperature, dielectric properties, cost, etc.

During operation the die-junction temperatures (T_j) should be maintained less than the value specified in Table 3. The temperature of the air cooling the component greatly depends upon the ambient inlet air temperature and the air temperature rise within the electronic cabinet. An electronic cabinet inlet-air temperature (T_a) may range from 30 to 40 °C. The air temperature rise within a cabinet (T_r) may be in the range of 5 to 10 °C. The thermal resistance of the thermal interface material (θ_{int}) is typically about 1 °C/W. Assuming a T_a of 30 °C, a T_r of 5 °C a CBGA package $\theta_{jc} = 0.095$, and a power consumption (P_d) of 3.0 Watts, the following expression for T_j is obtained:

Die-junction temperature: $T_j = 30\text{ °C} + 5\text{ °C} + (0.095\text{ °C/W} + 1.0\text{ °C/W} + R_{sa}) * 3.0\text{ W}$. For example, the heat sink-to-ambient thermal resistance (R_{sa}) versus airflow velocity is shown in this figure.

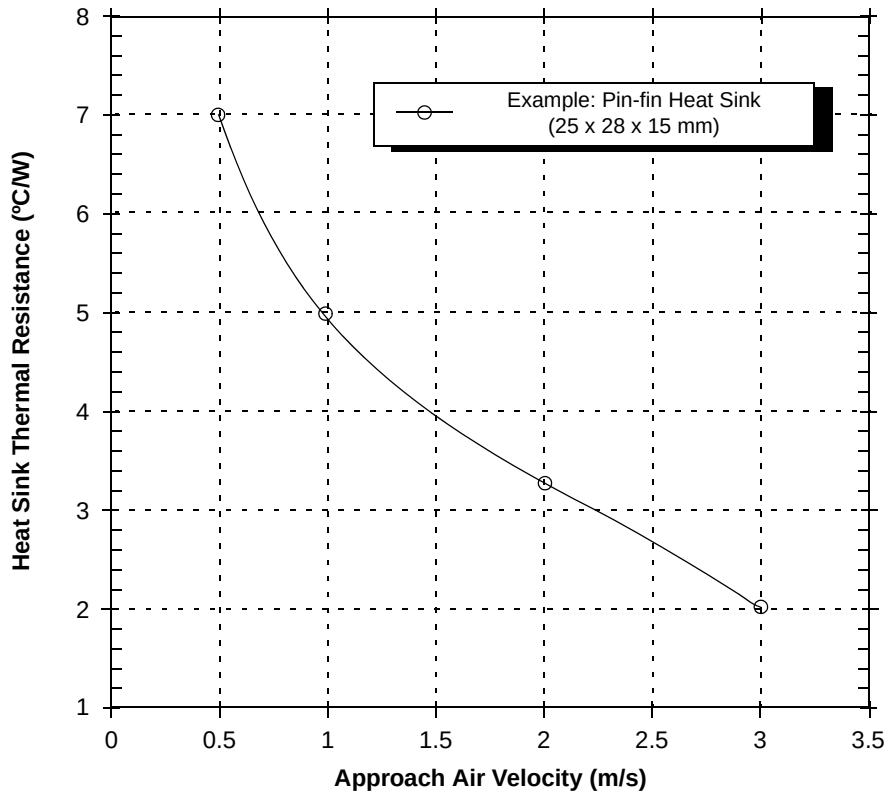


Figure 18. Example of Heat Sink-to-Ambient Thermal Resistance Versus Airflow Velocity

Assuming an air velocity of 0.5 m/s, we have an effective R_{sa} of 7 °C/W, thus

$$T_j = 30\text{ °C} + 5\text{ °C} + (0.095\text{ °C/W} + 1.0\text{ °C/W} + 7\text{ °C/W}) * 3.0\text{ W}, \quad \text{Eqn. 2}$$

resulting in a die-junction temperature of approximately 60 °C which is well within the maximum operating temperature of the component.

For a PBGA package, and assuming a T_a of 30 °C, a T_r of 5 °C a PBGA package $\theta_{jc} = 8$, and a power consumption (P_d) of 3.0 Watts, the following expression for die-junction temperature, T_j , is obtained as:

$$T_j = 30\text{ °C} + 5\text{ °C} + (8\text{ °C/W} + 1.0\text{ °C/W} + R_{sa}) * 3.0\text{ W} \quad \text{Eqn. 3}$$

Assuming an air velocity of 0.5 m/s, we have an effective R_{sa} of 7 °C/W, thus

$$T_j = 30^{\circ}\text{C} + 5^{\circ}\text{C} + (8^{\circ}\text{C/W} + 1.0^{\circ}\text{C/W} + 7^{\circ}\text{C/W}) * 3.0\text{ W}, \quad \text{Eqn. 4}$$

resulting in a die-junction temperature of approximately 83 °C that is well within the maximum operating temperature of the component. Commercially available heat sinks have different heat sink-to-ambient thermal resistances, and may or may not need air flow.

Though the die junction-to-ambient and the heat sink-to-ambient thermal resistances are a common figure-of-merit used for comparing the thermal performance of various microelectronic packaging technologies, one should exercise caution when only using this metric in determining thermal management because no single parameter can adequately describe three-dimensional heat flow. The final die-junction operating temperature is not only a function of the component-level thermal resistance, but the system-level design and its operating conditions. In addition to the component’s power consumption, a number of factors affect the final operating die-junction temperature—airflow, board population (local heat flux of adjacent components), heat sink efficiency, heat sink attach, heat sink placement, next-level interconnect technology, system air temperature rise, altitude, etc.

Due to the complexity and the many variations of system-level boundary conditions for today’s microelectronic equipment, the combined effects of the heat transfer mechanisms (radiation, convection, and conduction) may vary widely. For these reasons, we recommend using conjugate heat transfer models for the board, as well as, system-level designs. To expedite system-level thermal analysis, several “compact” thermal-package models are available within FLOTHERM®. These are available upon request.

9 Ordering Information

This figure provides the part numbering nomenclature for the PID7t-603e. Note that the individual part numbers correspond to a maximum processor core frequency. For available frequencies, contact your local Freescale sales office.

In addition to the processor frequency, the part numbering scheme also consists of a part modifier and application modifier. The part modifier indicates any enhancement(s) in the part from the original design. The application modifier may specify special bus frequencies or application conditions. Each part number also contains a revision code. This refers to the die mask revision number and is specified in the part numbering scheme for identification purposes only.

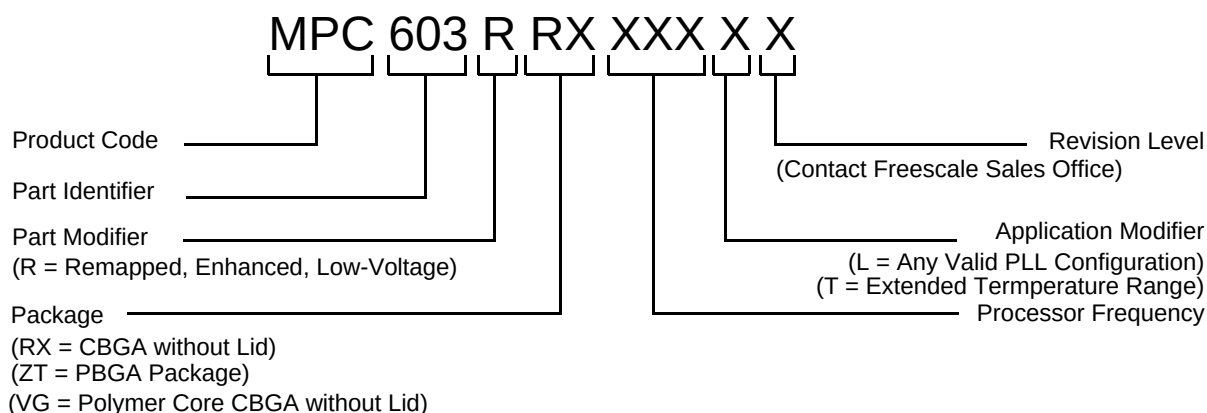


Figure 19. Part Number Key

10 Revision History

This table summarizes revision history for this document.

Table 13. Document Revision History

Rev. Number	Date	Substantive Change(s)
5	9/2011	• Updated to new Freescale template. • Added package info, VG = Polymer Core CBGA without Lid on Figure 19. • Deleted thermal heat sink and thermal interface vendor details from 8.6/-23 and 8.6.2/-26.

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